



**Features** 

Low On-Resistance Low Input Capacitance Fast Switching Speed ESD Protected Gate

IATF 16949 certified facilities.

**Mechanical Data** 

Package: TO252

DMP3007LK3Q

#### P-CHANNEL ENHANCEMENT MODE MOSFET

Lead-Free Finish; RoHS Compliant (Notes 1 & 2) Halogen and Antimony Free. "Green" Device (Note 3)

https://www.diodes.com/guality/product-definitions/

UL Flammability Classification Rating 94V-0 Moisture Sensitivity: Level 1 per J-STD-020

Solderable per MIL-STD-202, Method 208 @3

Weight: 0.315 grams (Approximate)

The DIODES<sup>™</sup> DMP3007LK3Q is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in

Package Material: Molded Plastic, "Green" Molding Compound;

Terminal Finish - Matte Tin Annealed over Copper Lead Frame.

#### **Product Summary**

BVDSS	Rds(on) Max	I <sub>D</sub> Max TA = +25°C
	7.0mΩ @ V <sub>GS</sub> = -10V	-18.5A
-30V	10.0mΩ @ V <sub>GS</sub> = -4.5V	-15.5A

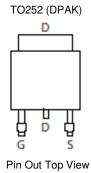
# **Description and Applications**

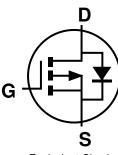
This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Backlighting
- Power management functions
- DC-DC converters



Top View





Equivalent Circuit

#### Ordering Information (Note 4)

Part Number	Paakaga	Packing		
Part Number	Package	Qty.	Carrier	
DMP3007LK3Q-13	TO252 (DPAK)	2,500	Tape & Reel	

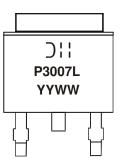
Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**



)'' = Manufacturer's Marking
P3007L = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 22 = 2022)
WW = Week Code (01 to 53)



#### **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			VDSS	-30	V
Gate-Source Voltage			V <sub>GSS</sub>	±20	V
Continuous Drain Current, VGS = -10V (Note 6)	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	-18.5 -15	A
Maximum Continuous Body Diode Forward Current (Note 6)			ls	-4.5	A
Pulsed Drain Current (380µs Pulse, Duty Cycle = 1%)			Ідм	-250	A
Pulsed Body Diode Forward Current (380µs Pulse, Duty Cycle = 1%)			lsм	-250	A
Avalanche Current, L = 1mH (Note 7)			las	-16	A
Avalanche Energy, L = 1mH (Note 7)			Eas	130	mJ

## **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	PD	1.5	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	RθJA	81	°C/W
Total Power Dissipation (Note 6)	TA = +25°C	PD	3.0	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	RθJA	42	°C/W
Thermal Resistance, Junction to Case (Note 6)	R <sub>0JC</sub>	1.5	°C/W	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

## Electrical Characteristics (T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BVDSS	-30	—	—	V	$V_{GS} = 0V, I_{D} = -250 \mu A$	
Zero Gate Voltage Drain Current	IDSS	_	—	-1	μA	$V_{DS} = -24V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS	_	—	±10	μA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)			•		•	·	
Gate Threshold Voltage	VGS(TH)	-1.0	—	-2.8	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$	
Static Drain-Source On-Resistance	Deserve	_	5.8	7		V <sub>GS</sub> = -10V, I <sub>D</sub> = -17A	
Static Drain-Source On-Resistance	RDS(ON)	_	8.2	10	mΩ	$V_{GS} = -4.5V, I_D = -15A$	
Diode Forward Voltage	Vsd	_	-0.7	-1.2	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = -1A	
DYNAMIC CHARACTERISTICS (Note 9)			•		•		
Input Capacitance	Ciss	_	2826	—	pF		
Output Capacitance	Coss	_	606	—	pF	VDS = -15V, VGS = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	Crss	_	305	—	pF		
Gate Resistance	Rg	—	22.8	-	Ω	$V_{DS} = 0V, V_{GS} = 0V,$ f = 1.0MHz	
Total Gate Charge (V <sub>GS</sub> = -4.5V)	Qg	_	31.2	—	nC		
Total Gate Charge (V <sub>GS</sub> = -10V)	Qg	_	64.2	—	nC		
Gate-Source Charge	Qgs	_	10.6	—	nC	VDS = -15V, ID = -11.5A	
Gate-Drain Charge	Q <sub>gd</sub>	_	11.6	—	nC		
Turn-On Delay Time	t <sub>D(ON)</sub>	_	4.8	—	ns		
Turn-On Rise Time	tR	_	4.3	—	ns	V <sub>DD</sub> = -15V, V <sub>GS</sub> = -10V,	
Turn-Off Delay Time	tD(OFF)	_	306	—	ns	R <sub>g</sub> = 6Ω, I <sub>D</sub> = -11.5A	
Turn-Off Fall Time	tF	_	125	—	ns	1	
Reverse Recovery Time	trr	_	19	—	ns		
Reverse Recovery Charge	Qrr		9.8	—	nC	$I_{\rm S} = -11.5$ A, dl/dt = 100A/µs	

Notes: 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.

6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.

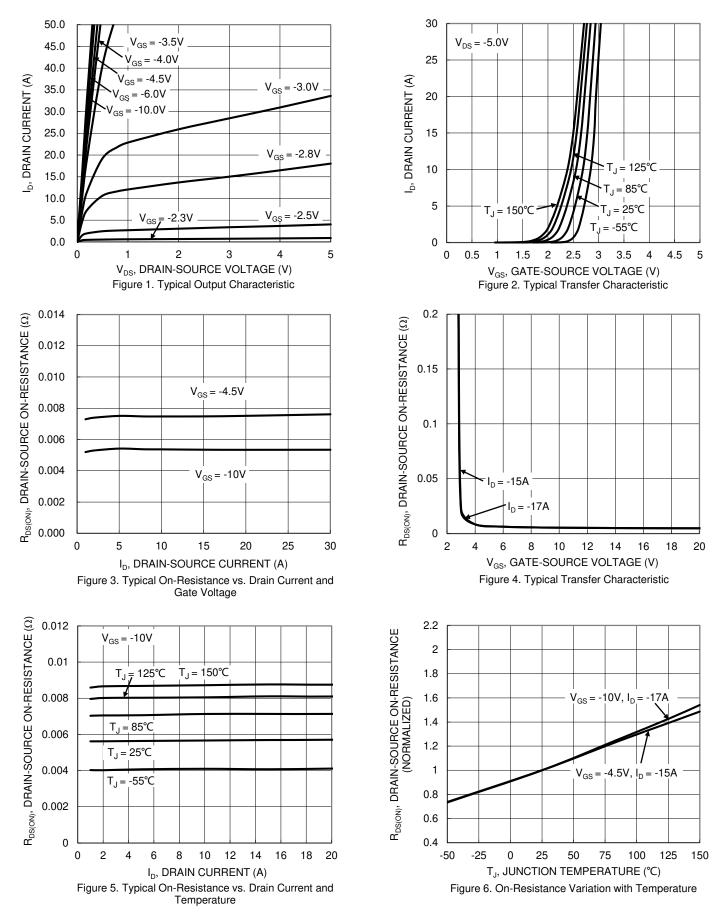
7. I<sub>AS</sub> and E<sub>AS</sub> ratings are based on low frequency and duty cycles to keep  $T_J$  = +25°C.

8. Short duration pulse test used to minimize self-heating effect.

9. Guaranteed by design. Not subject to product testing.

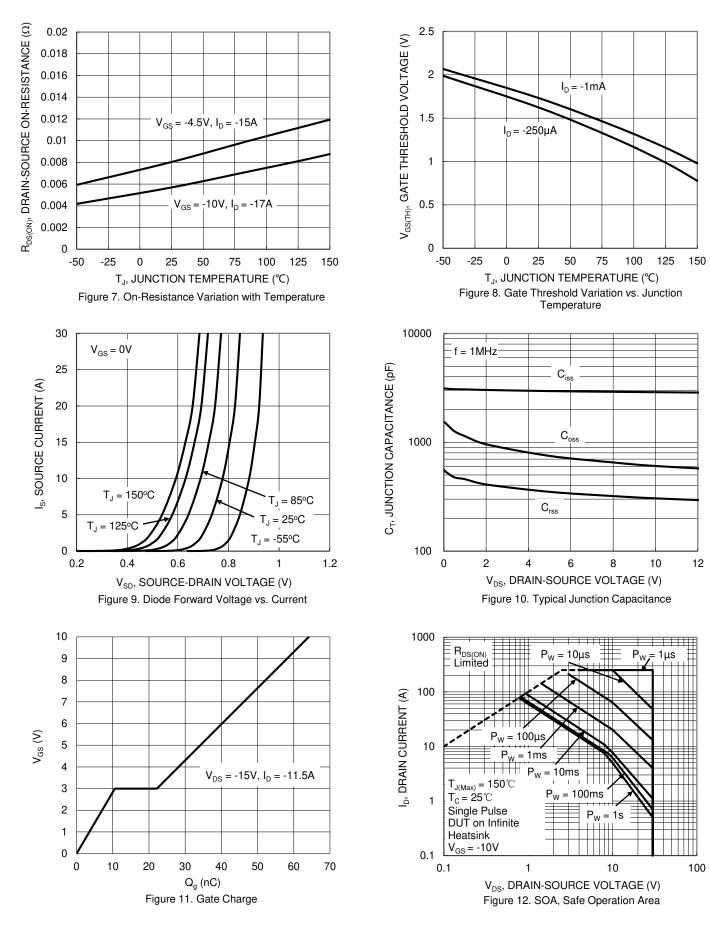


## DMP3007LK3Q

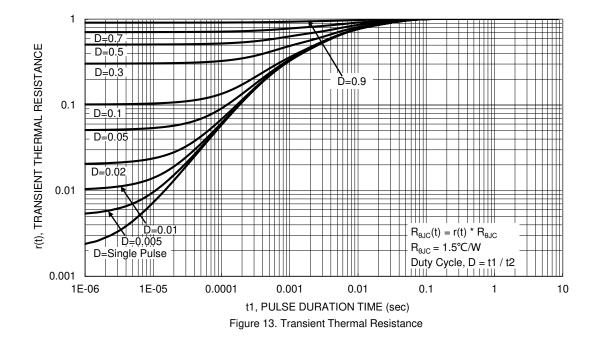




# DMP3007LK3Q



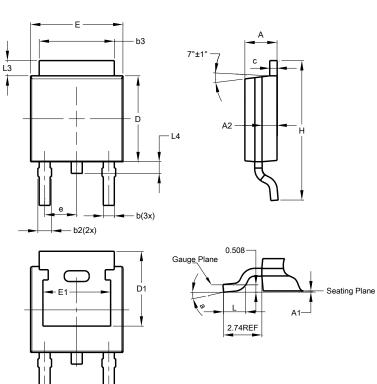






## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

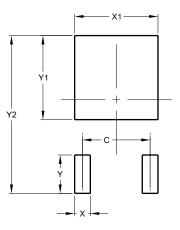


	TO252 (DPAK)						
Dim	Min	Max	Тур				
Α	2.19	2.39	2.29				
<b>A</b> 1	0.00	0.13	0.08				
A2	0.97	1.17	1.07				
b	0.64	0.88	0.783				
b2	0.76	1.14	0.95				
b3	5.21	5.50	5.33				
С	0.45	0.58	0.531				
D	6.00	6.20	6.10				
D1	5.21						
е	2.286 BSC						
Е	6.45	6.70	6.58				
E1	4.32	-					
Η	9.40	10.41	9.91				
L	1.40	1.78	1.59				
L3	0.88	1.27	1.08				
L4	0.64	1.02	0.83				
а	0°	10°					
All	All Dimensions in mm						

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.





Dimensions	Value (in mm)			
С	4.572			
Х	1.060			
X1	5.632			
Y	2.600			
Y1	5.700			
Y2	10.700			

# TO252 (DPAK)



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